NSN 5961-01-062-0665

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-062-0665 **Inclosure Material:** Metal **Overall Length:** 1.675 inches **Overall Diameter:** 1.063 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 1.227 inches **Thread Size:** 0.375 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 250.0 repetitive peak reverse voltage, peak total value and 175.0 reverse voltage, total rms **Current Rating Per Characteristic:** 150.00 amperes source cutoff current horsepower metric **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

Fiig:

A110a0